NSN 5961-01-042-4863

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View Online at https://aerobasegroup.com/nsn/5961-01-042-4863
Inclosure Material:
Metal
Overall Length:
Between 0.245 inches and 0.295 inches
Overall Height:
Between 0.245 inches and 0.295 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.420 inches and 0.440 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
65.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage
static, collector open
Current Rating Per Characteristic:
1.50 amperes source cutoff current
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/341 government specification
Shelf Life:
N/a

NI

Unit Of Measure:

Demilitarization:

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